For m PTO-1449 (Modified)	U.S. Department of Commerce	Atty. Docket No.	Serial No.		
Ī	Patent and Trademark Office	30205/39511	To be Assigned		
		Applicant	10/273 485		
INFORMATION DISC	CLOSURE STATEMENT	Seong Hwan Park			
		Filing Date	Group 2813		
		November 26, 2003	-To-be Assigned		

		U.S. PATE	NT DOCUMENT	rs .		
*Examiner Initials	Document Number	Issue Date	Name	Class	Subclass	Filing Date if Appropriate
				 		
	\rightarrow					<u> </u>

7.7		F	OREIGN PA	TENT DO	CUMENT	`S.	***************************************	
*Examiner	Publication Date Country Class		Class	Subclass	ubclass Translation			
							Yes	No

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)				
TN	Fujimura et al., "Ashing of the Ion Implanted Resist Layer," Digest of Papers			
110	1989 2 nd MicroProcess Conference, July 2-5, 1989.			

EXAMINER DATE CONSIDERED 2/3/05

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.